Electronic Supplementary Information for:

## Graphene Oxide in Carbon Nitride: From Easily Processed Precursors to a Composite Material with Enhanced Photoelectrochemical Activity and Longterm Stability

Guiming Peng,<sup>‡a,b</sup> Jiani Qin,<sup>‡a</sup> Michael Volokh,<sup>a</sup> Chong Liu<sup>b</sup> and Menny Shalom<sup>\*a</sup>

<sup>a</sup> Department of Chemistry and Ilse Katz Institute for Nanoscale Science and Technology, Ben-Gurion University of the Negev, Beer-Sheva 8410501, Israel.

<sup>b</sup> Institute for Molecular Engineering, University of Chicago, Chicago, Illinois 60637, USA.

‡Authors with equal contribution

\*E-mail: mennysh@bgu.ac.il

## **Experimental characterization**

The morphology of the samples was examined by scanning electron microscopy (SEM, JEOL JSM-7400F equipped with a FEG source, operated at 3.5 kV). X-ray diffraction (XRD) patterns were collected using PANalytical's Empyrean diffractometer. X-ray photoelectron spectroscopy (XPS) was collected on Thermo Fisher Scientific ESCALAB 250 using monochromated K $\alpha$  X-rays (1486.6 eV). Fourier transform infrared spectroscopy (FTIR) was collected using a Thermo Scientific Nicolet iN 10Mx infrared microscope. UV-vis spectra were obtained using a Cary 100 spectrophotometer. Fluorescence measurements were collected using an Edinburgh instruments FLS920P Fluorimeter. Viscosity measurements were performed on an AR 2000 Rheometer (from TA Instruments) at room temperature. Gas chromatography (GC) data was collected using an Agilent 6850 GC equipped with an Agilent HP5-MS column.



 $Fig. \, S1 \ {\rm Photographs} \ of \ melamine \ paste \ and \ melamine/GO \ pastes \ with \ different \ GO \ amounts \ (from$ 

x = 0 to x = 0.75) at preparation (top row) and after 5 days (bottom row).



**Fig. S2** Photograph of a melamine film (M) and melamine/GO films (MGO $_x$ ) on FTO before calcination.



Fig. S3 (a-c) SEM images of MGO<sub>0.25</sub>. (d-f) SEM images of MGO<sub>0.75</sub>. The arrows indicate the

presence of GO.



Fig. S4 FTIR spectra of GO, melamine powder (pristine), and MGO<sub>0.5</sub> film.



Fig. S5 XRD patterns of melamine and MGO<sub>0.5</sub> films.



**Fig. S6** (a) Photographs of dicyandiamide paste (DCDA) and dicyandiamide/ $GO_{0.5}$  paste (DCDAGO<sub>0.5</sub>). (b) Photographs of a fluidity test on glass slide. (c) Photographs of DCDA and DCDAGO<sub>0.5</sub> films on FTO. (d, e) SEM images of the DCDAGO<sub>0.5</sub> film. (f) SEM image of the CN/rGO film after calcination of DCDAGO<sub>0.5</sub> under N<sub>2</sub> atmosphere at 550 °C for 4 h. (g) Photocurrent of the CN/rGO<sub>0.5</sub> electrode under one-sun illumination in 0.1 M KOH, which was prepared by calcination of DCDAGO<sub>0.5</sub>.

It is noted that a viscous paste cannot be prepared using DCDA only. Similarly, DCDA suspension cannot be coated onto FTO to form a uniform layer (Fig. S6a–b). However, after the addition of GO, the viscosity is increased (manifested in slower flow rate shown in Fig. S6b), and

the coating ability is greatly improved (Fig. S6c). GO nanosheets can be observed embedded within the DCDA microcrystals (Fig. S6e), speaking for its binder role in DCDA preparation. After thermal condensation, CN/rGO film can be obtained. The SEM image shows that the CN/rGO film is composed of a continuous CN layer on FTO, while on the top surface there are standing microstructures (Fig. S6f). The corresponding electrode after calcination generated a photocurrent of 63.8  $\mu$ A cm<sup>-2</sup> under one-sun illumination (Figure S6g).



**Fig. S7** FTIR spectra of GO and the reduced graphene oxide (rGO) obtained by thermal reduction of GO at 550 °C for 4 h under N<sub>2</sub>. Clearly, most of the oxygen-containing functionalities (-OH, C=O, and C-O-C) are removed after the thermal treatment, showing that the GO is reduced to rGO using this method.



Fig. S8 Photographs of the CN and  $CN/rGO_x$  (x = 0.25, 0.5, 0.75) electrodes.



Fig. S9 Top-view SEM images of (a) CN, (b) CN/rGO<sub>0.25</sub>, (c) CN/rGO<sub>0.5</sub>, and (d) CN/rGO<sub>0.75</sub>.



Fig. S10 Cross-sectional SEM image of (a) CN, and (b) CN/rGO<sub>0.5</sub> electrodes (on FTO).



**Fig. S11** CN/rGO<sub>0.5</sub> films of different thickness prepared by 1, 2, and 3 scotch tape layers during doctor-blade coating process. The number of scotch tape layers is indicated on each image. The thickness of the bottom continuous layers is  $\sim$ 7,  $\sim$ 23, and  $\sim$ 57 µm, respectively.



Fig. S12 FTIR spectra of CN and CN/rGO<sub>0.5</sub>.



Fig. S13 N1s XPS of (a) CN, and of (b) CN/rGO<sub>0.5</sub>.



Fig. S14 C1s and N1s XPS spectra of rGO (after the same thermal process of the rGO-containing

electrodes).



Fig. S15 UV-vis spectra of CN and CN/rGO<sub>0.5</sub>.



**Fig. S16** (a) Mott-Schottky plots, and (b) proposed bandgap diagram of the CN and  $CN/rGO_{0.5}$  electrodes.



**Fig. S17** Photocurrents of CN and CN/rGO<sub>*x*</sub> electrodes at 1.23 V *vs*. RHE in 0.1 M KOH aqueous solution upon cycling on/off 1-sun illumination (chronoamperometry).



**Fig. S18** Photocurrents of CN and CN/rGO<sub>0.5</sub> electrodes at 1.23 V *vs.* RHE in 0.1 M KOH aqueous solution during 3 h continuous 1-sun illumination.



Fig. S19 Open circuit potential of (a) CN electrode and (b) CN/rGO<sub>0.5</sub> electrode.



Fig. S20 Nyquist plots of (a) CN, and (b) CN/rGO<sub>0.5</sub> at different potentials (vs. Ag/AgCl) in 0.1

M KOH aqueous solution. (c) The equivalent circuit for the fitting of Nyquist plots.



**Fig. S21** Fluorescence spectra of CN, CN/rGO<sub>0.25</sub>, CN/rGO<sub>0.5</sub>, and CN/rGO<sub>0.75</sub>. The excitation wavelength is 370 nm.



**Fig. S22** N<sub>2</sub> adsorption-desorption isotherms plots of the CN and CN/rGO<sub>0.5</sub> powder scratched from the electrodes. Calculated BET surface areas are 8.97 m<sup>2</sup> g<sup>-1</sup> and 14.73 m<sup>2</sup> g<sup>-1</sup> for the CN and CN/rGO<sub>0.5</sub>, respectively.



**Fig. S23** Photocurrent densities when illuminated from front- and back-side of (a) CN, and (b) CN/rGO<sub>0.5</sub> electrodes at 1.23 V *vs.* RHE in 0.1 M KOH.



**Fig. S24** Photocurrent densities when illuminated from front and back side of  $CN/rGO_{0.5}$  electrodes with different thicknesses at 1.23 V *vs.* RHE in 0.1 M KOH. (a) Chronoamperometry of 7 µm thick electrode, (b) Chronoamperometry of 57 µm thick electrode. (c) The ratios of the photocurrent when illuminated from the frontside relative to illumination from the backside of  $CN/rGO_{0.5}$  electrodes of each thickness.



**Fig. S25** LSV curves of the CN and CN/rGO<sub>0.5</sub> electrodes in 0.1 M KOH (solid lines) and 0.1 M KOH aqueous solutions containing 10% (v/v) TEOA (dashed lines) as a hole scavenger. (b) The charge transfer efficiency (defined as the ratio between the photocurrent in 0.1 M KOH divided and that in 0.1 M KOH containing the hole scavenged) plots of CN and CN/rGO<sub>0.5</sub> electrodes. The hole scavenger used is 10% (v/v) TEOA (triethanolamine, 99%, Carl Roth) in 0.1 M KOH aqueous solution.



**Fig. S26** Gas chromatograms after different photoelectrochemical measurement durations (0, 1, 2, and 3 h) when using (a) CN/rGO<sub>0.5</sub> and (b) CN as the photoelectrocatalyst under constant 1-sun

illumination. The electrodes are biased at 1.23 V vs. RHE, while the electrolyte is 0.1 M KOH containing 10% (v/v) TEOA.



Fig. S27 H<sub>2</sub> production as a function of time.

Table S1. Elemental composition of the CN and CN/rGO<sub>0.5</sub> obtained by XPS measurements.

| Sample                | C (atom%) | N (atom%) | O (atom%) | C/N atomic ratio |
|-----------------------|-----------|-----------|-----------|------------------|
| CN                    | 43.89     | 55.27     | 0.84      | 0.79             |
| CN/rGO <sub>0.5</sub> | 44.55     | 46.65     | 8.8       | 0.95             |

Table S2. Summary of PEC performances of CN-based photoanodes

| Catalyst                                   | Photocurrent<br>(µA cm <sup>-2</sup> ) | Potential<br><i>vs.</i> RHE (V) | Onset potential<br>vs. RHE <sup>a</sup> | Electrolyte  | Light intensity                  | Ref.         |
|--|--|---------------------------------|---|--|----------------------------------|--------------|
| <i>In situ</i> grown porous<br>CN/rGO film | 124.5                                  | 1.23                            | 0.3                                     | 0.1 M KOH  | 100 mW cm <sup>-2</sup> , AM 1.5 | This<br>work |
|  | 272                                    | 1.23                            | N/A                                     | 0.1 M KOH + 10%<br>TEOA  | 100 mW cm <sup>-2</sup> , AM 1.5 |              |
| Crystalline CN film                        | 116                                    | 1.23                            | 0.25                                    | 0.1 M KOH  | 100 mW cm <sup>-2</sup> , AM 1.5 | [1]          |
| CN-rGO film                                | 72                                     | 1.23                            | 0.75                                    | 0.1 M KOH  | 100 mW cm <sup>-2</sup> , AM 1.5 | [2]          |
| CN   | 63                                     | 1.23                            | N/A                                     | 0.1 M Na <sub>2</sub> SO <sub>4</sub>  | 100 mW cm <sup>-2</sup> , AM 1.5 | [3]          |
| CN   | 30.2                                   | 1.23                            | N/A                                     | 0.2 M Na <sub>2</sub> SO <sub>4</sub>  | 500 W                            | [4]          |
| Porous CN film                             | 12                                     | 1.23                            | N/A                                     | 0.1 M KOH  | 100 mW cm <sup>-2</sup> , AM 1.5 | [5]          |
| Boron-doped CN                             | 103.2                                  | 1.23                            | N/A (~0.4)                              | 0.1 M Na <sub>2</sub> SO <sub>4</sub>  | 100 mW cm <sup>-2</sup> , AM 1.5 | [6]          |
| CN/rGO/NiFe-layered<br>double hydroxide    | 72.9                                   | 1.22                            | 0.48                                    | 0.01 M Na <sub>2</sub> SO <sub>4</sub>   | 100 mW cm <sup>-2</sup> , AM 1.5 | [7]          |
| 3% Ni-CN                                   | 69.8                                   | 1.23                            | N/A                                     | 0.1 M KOH  | AM 1.5                           | [8]          |
| Compact CN film                            | 120                                    | 1.55                            | N/A                                     | 0.1 M Na <sub>2</sub> SO <sub>4</sub><br>+ 0.1 M Na <sub>2</sub> SO <sub>3</sub> + 0.01<br>M Na <sub>2</sub> S | 100 mW cm <sup>-2</sup> , AM 1.5 | [9]          |
| Compact CN film                            | 100                                    | 1.23                            | N/A                                     | 0.1 M Na <sub>2</sub> SO <sub>4</sub><br>+ 0.1 M Na <sub>2</sub> SO <sub>3</sub> + 0.01<br>M Na <sub>2</sub> S | 100 mW cm <sup>-2</sup> , AM 1.5 | [10]         |

| CN film          | 228.2 | 1.23 | N/A (~0.65) | 0.2 M Na <sub>2</sub> SO <sub>4</sub> | 150 W Xe lamp, AM 1.5            | [11] |
|------------------|-------|------|-------------|---------------------------------------|----------------------------------|------|
| S-doped CN       | 60    | 1.23 | N/A         | 0.1 M KOH                             | 50 W white light                 | [12] |
| CN nanorod array | 120.5 | 1.23 | N/A (~0.4)  | 0.1 M Na <sub>2</sub> SO <sub>4</sub> | 100 mW cm <sup>-2</sup> , AM 1.5 | [13] |

<sup>*a*</sup> The numbers in parentheses in the onset potential column are estimated from the published LSV curves in the corresponding paper.

## **ESI References**

- 1 G. Peng, J. Albero, H. Garcia and M. Shalom, Angew. Chem. Int. Ed., 2018, 57, 15807–15811.
- 2 G. Peng, M. Volokh, J. Tzadikov, J. Sun and M. Shalom, Adv. Energy Mater., 2018, 8, 1800566.
- 3 X. Lv, M. Cao, W. Shi, M. Wang and Y. Shen, Carbon, 2017, 117, 343-350.
- 4 J. Liu, H. Wang, Z. P. Chen, H. Moehwald, S. Fiechter, R. van de Krol, L. Wen, L. Jiang and M. Antonietti, *Adv. Mater.*, 2015, **27**, 712.
- 5 G. Peng, L. Xing, J. Barrio, M. Volokh and M. Shalom, *Angew. Chem. Int. Ed.*, 2018, **57**, 1186–1192.
- 6 W. J. Ong, L. L. Tan, Y. H. Ng, S. T. Yong and S. P. Chai, Chem. Rev., 2016, 116, 7159-7329.
- 7 Y. Hou, Z. Wen, S. Cui, X. Feng and J. Chen, Nano Lett., 2016, 16, 2268–2277.
- 8 W. Zhang, J. Albero, L. Xi, K. M. Lange, H. Garcia, X. Wang and M. Shalom, *ACS Appl. Mater*. *Interfaces*, 2017, **9**, 32667–32677.
- 9 J. Bian, Q. Li, C. Huang, J. Li, Y. Guo, M. Zaw and R.-Q. Zhang, *Nano Energy*, 2015, **15**, 353–361.
- 10 J. Bian, L. Xi, C. Huang, K. M. Lange, R.-Q. Zhang and M. Shalom, *Adv. Energy Mater.*, 2016, 6, 1600263.
- 11 W. Xiong, S. Chen, M. Huang, Z. Wang, Z. Lu and R.-Q. Zhang, *ChemSusChem*, 2018, **11**, 2497–2501.
- 12 J. Xu, S. Cao, T. Brenner, X. Yang, J. Yu, M. Antonietti and M. Shalom, *Adv. Funct. Mater.*, 2015, **25**, 6265–6271.

13 B. Guo, L. Tian, W. Xie, A. Batool, G. Xie, Q. Xiang, S. U. Jan, R. Boddula and J. R. Gong, *Nano Lett.*, 2018, **18**, 5954–5960.